

# FDS89141

## Dual N-Channel PowerTrench® MOSFET

100 V, 3.5 A, 62 mΩ

### Features

- Max  $r_{DS(on)}$  = 62 mΩ at  $V_{GS} = 10$  V,  $I_D = 3.5$  A
- Max  $r_{DS(on)}$  = 100 mΩ at  $V_{GS} = 6$  V,  $I_D = 2.8$  A
- High performance trench technology for extremely low  $r_{DS(on)}$
- High power and current handling capability in a widely used surface mount package
- 100% UIL Tested
- RoHS Compliant

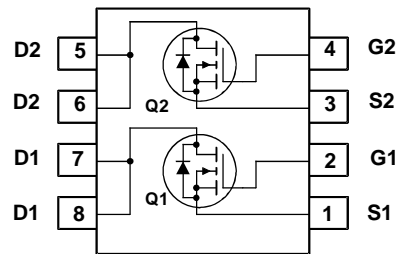
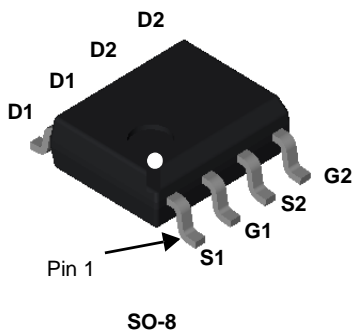


### General Description

This N-Channel MOSFET is produced using Fairchild Semiconductor's advanced Power Trench® process that has been optimized for  $r_{DS(on)}$ , switching performance and ruggedness.

### Applications

- Synchronous Rectifier
- Primary Switch For Bridge Topology



### MOSFET Maximum Ratings $T_A = 25^\circ\text{C}$ unless otherwise noted

Symbol	Parameter	Ratings	Units
$V_{DS}$	Drain to Source Voltage	100	V
$V_{GS}$	Gate to Source Voltage	$\pm 20$	V
$I_D$	Drain Current -Continuous	3.5	A
	-Pulsed	18	
$E_{AS}$	Single Pulse Avalanche Energy (Note 3)	37	mJ
$P_D$	Power Dissipation $T_A = 25^\circ\text{C}$ (Note 1a)	31	W
	Power Dissipation $T_A = 25^\circ\text{C}$ (Note 1b)	1.6	
$T_J, T_{STG}$	Operating and Storage Junction Temperature Range	-55 to +150	$^\circ\text{C}$

### Thermal Characteristics

$R_{\theta JC}$	Thermal Resistance, Junction to Case (Note 1)	4.0	$^\circ\text{C/W}$
$R_{\theta JA}$	Thermal Resistance, Junction to Ambient (Note 1a)	78	

### Package Marking and Ordering Information

Device Marking	Device	Package	Reel Size	Tape Width	Quantity
FDS89141	FDS89141	SO-8	13 "	12 mm	2500 units

## Electrical Characteristics $T_J = 25^\circ\text{C}$ unless otherwise noted

Symbol	Parameter	Test Conditions	Min	Typ	Max	Units
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### Off Characteristics

$BV_{DSS}$	Drain to Source Breakdown Voltage	$I_D = 250 \mu\text{A}, V_{GS} = 0 \text{ V}$	100			V
$\frac{\Delta BV_{DSS}}{\Delta T_J}$	Breakdown Voltage Temperature Coefficient	$I_D = 250 \mu\text{A}$ , referenced to $25^\circ\text{C}$		69		mV/ $^\circ\text{C}$
$I_{DSS}$	Zero Gate Voltage Drain Current	$V_{DS} = 80 \text{ V}, V_{GS} = 0 \text{ V}$			1	$\mu\text{A}$
$I_{GSS}$	Gate to Source Leakage Current	$V_{GS} = \pm 20 \text{ V}, V_{DS} = 0 \text{ V}$			$\pm 100$	nA

### On Characteristics

$V_{GS(th)}$	Gate to Source Threshold Voltage	$V_{GS} = V_{DS}, I_D = 250 \mu\text{A}$	2	3.1	4	V
$\frac{\Delta V_{GS(th)}}{\Delta T_J}$	Gate to Source Threshold Voltage Temperature Coefficient	$I_D = 250 \mu\text{A}$ , referenced to $25^\circ\text{C}$		-9		mV/ $^\circ\text{C}$
$r_{DS(on)}$	Static Drain to Source On Resistance	$V_{GS} = 10 \text{ V}, I_D = 3.5 \text{ A}$		47	62	m $\Omega$
		$V_{GS} = 6 \text{ V}, I_D = 2.8 \text{ A}$		63	100	
		$V_{GS} = 10 \text{ V}, I_D = 3.5 \text{ A}, T_J = 125^\circ\text{C}$		81	107	
$g_{FS}$	Forward Transconductance	$V_{DS} = 10 \text{ V}, I_D = 3.5 \text{ A}$		14.7		S

### Dynamic Characteristics

$C_{iss}$	Input Capacitance	$V_{DS} = 50 \text{ V}, V_{GS} = 0 \text{ V}, f = 1 \text{ MHz}$		299	398	pF
$C_{oss}$	Output Capacitance			70	93	pF
$C_{rss}$	Reverse Transfer Capacitance			4.7	7	pF
$R_g$	Gate Resistance			1.0		$\Omega$

### Switching Characteristics

$t_{d(on)}$	Turn-On Delay Time	$V_{DD} = 50 \text{ V}, I_D = 3.5 \text{ A}, V_{GS} = 10 \text{ V}, R_{GEN} = 6 \Omega$		5	10	ns
$t_r$	Rise Time			1.4	10	ns
$t_{d(off)}$	Turn-Off Delay Time			9.8	20	ns
$t_f$	Fall Time			2.2	10	ns
$Q_{g(TOT)}$	Total Gate Charge		$V_{GS} = 0 \text{ V to } 10 \text{ V}$		5.1	7.1
$Q_{g(TOT)}$	Total Gate Charge	$V_{GS} = 0 \text{ V to } 5 \text{ V}$		2.9	4.1	nC
$Q_{gs}$	Gate to Source Charge	$V_{DD} = 50 \text{ V}, I_D = 3.5 \text{ A}$		1.4		nC
$Q_{gd}$	Gate to Drain "Miller" Charge			1.3		nC

### Drain-Source Diode Characteristics

$V_{SD}$	Source to Drain Diode Forward Voltage	$V_{GS} = 0 \text{ V}, I_S = 3.5 \text{ A}$ (Note 2)		0.8	1.3	V
		$V_{GS} = 0 \text{ V}, I_S = 2 \text{ A}$ (Note 2)		0.8	1.2	
$t_{rr}$	Reverse Recovery Time	$I_F = 3.5 \text{ A}, di/dt = 100 \text{ A}/\mu\text{s}$		33	53	ns
$Q_{rr}$	Reverse Recovery Charge			23	37	nC

#### NOTES:

- $R_{\theta JA}$  is determined with the device mounted on a  $1 \text{ in}^2$  pad 2 oz copper pad on a  $1.5 \times 1.5 \text{ in.}$  board of FR-4 material.  $R_{\theta JC}$  is guaranteed by design while  $R_{\theta CA}$  is determined by the user's board design.



a)  $78^\circ\text{C/W}$  when mounted on a  $1 \text{ in}^2$  pad of 2 oz copper



b)  $135^\circ\text{C/W}$  when mounted on a minimum pad

- Pulse Test: Pulse Width  $< 300 \mu\text{s}$ , Duty cycle  $< 2.0\%$ .
- Starting  $T_J = 25^\circ\text{C}$ ,  $L = 3.0 \text{ mH}$ ,  $I_{AS} = 5.0 \text{ A}$ ,  $V_{DD} = 100 \text{ V}$ ,  $V_{GS} = 10 \text{ V}$ .

**Typical Characteristics ( N-Channel)**  $T_J = 25^\circ\text{C}$  unless otherwise noted

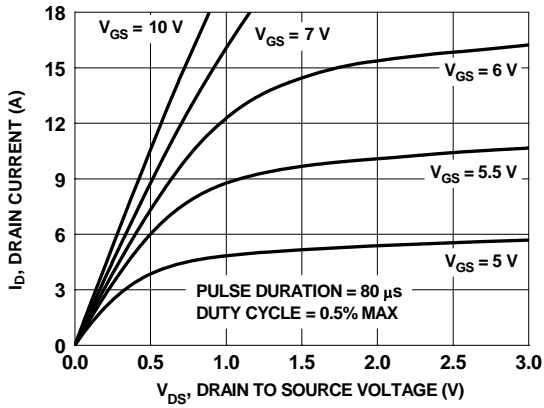


Figure 1. On-Region Characteristics

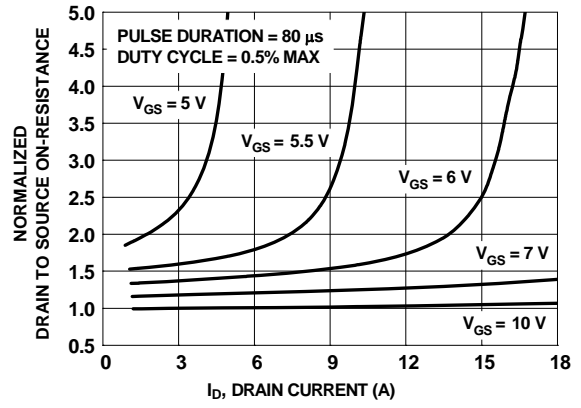


Figure 2. Normalized On-Resistance vs Drain Current and Gate Voltage

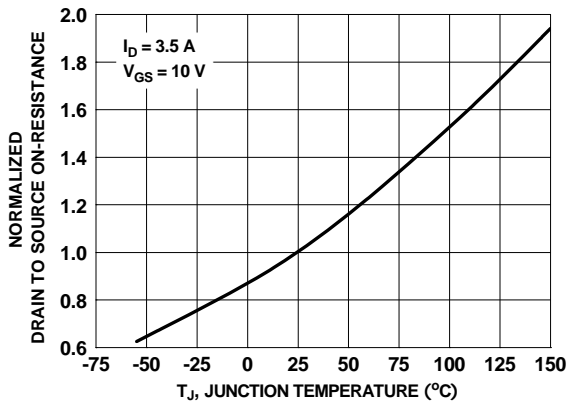


Figure 3. Normalized On-Resistance vs Junction Temperature

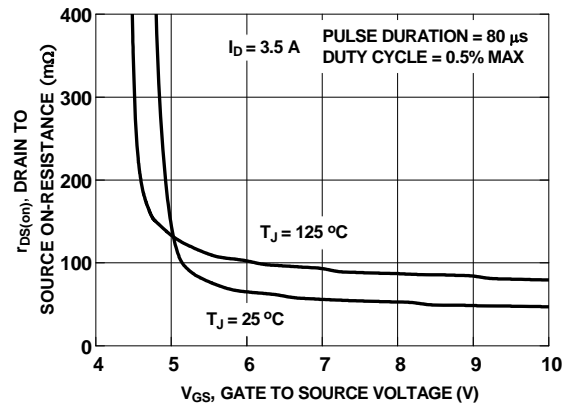


Figure 4. On-Resistance vs Gate to Source Voltage

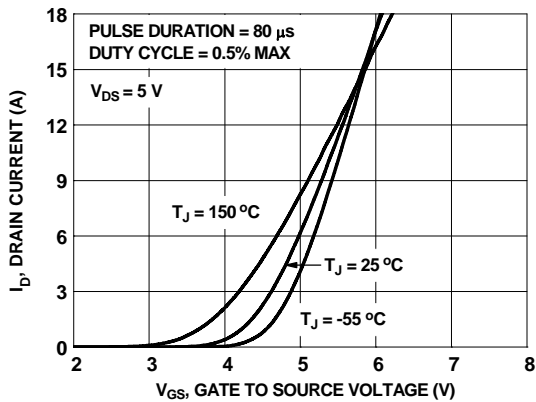


Figure 5. Transfer Characteristics

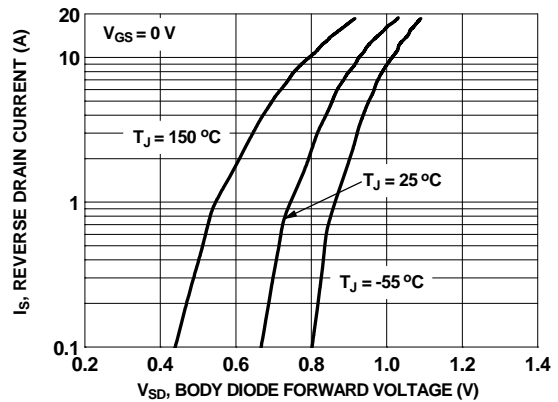
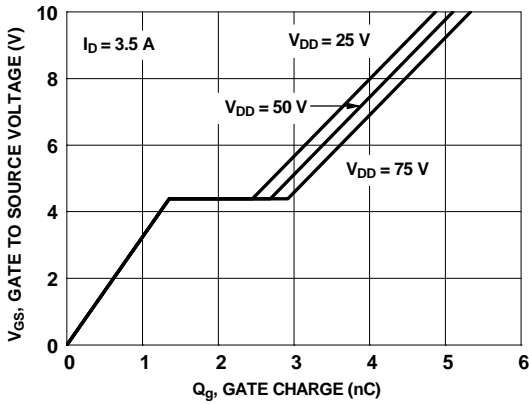
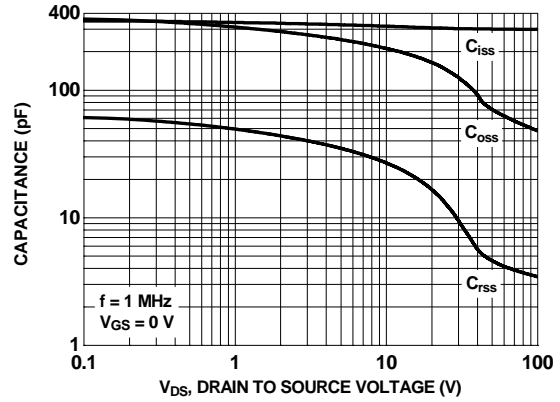


Figure 6. Source to Drain Diode Forward Voltage vs Source Current

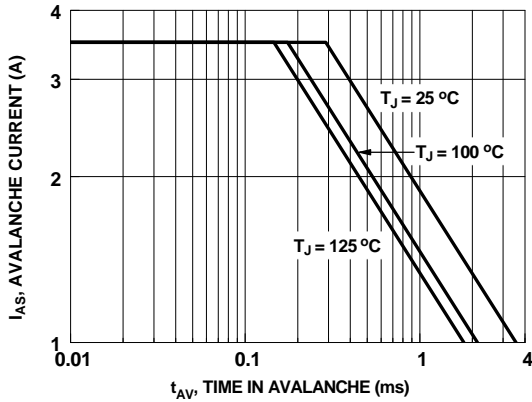
**Typical Characteristics ( N-Channel)**  $T_J = 25^\circ\text{C}$  unless otherwise noted



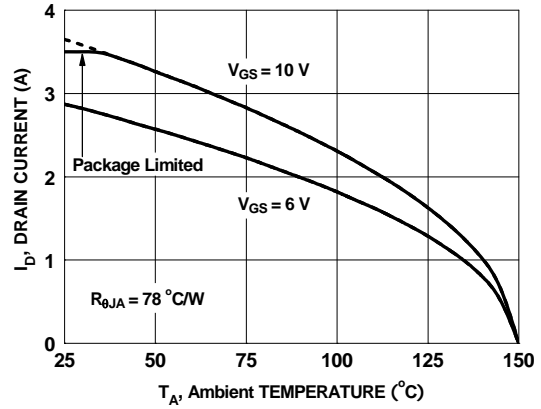
**Figure 7. Gate Charge Characteristics**



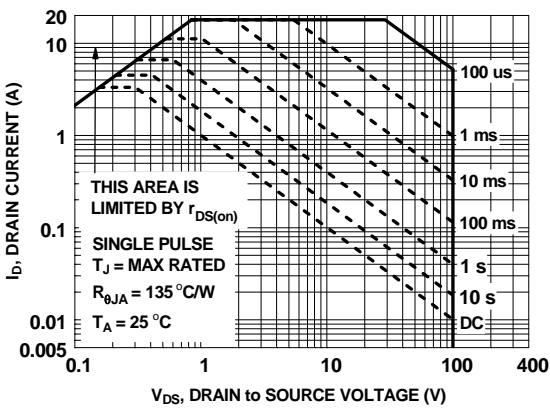
**Figure 8. Capacitance vs Drain to Source Voltage**



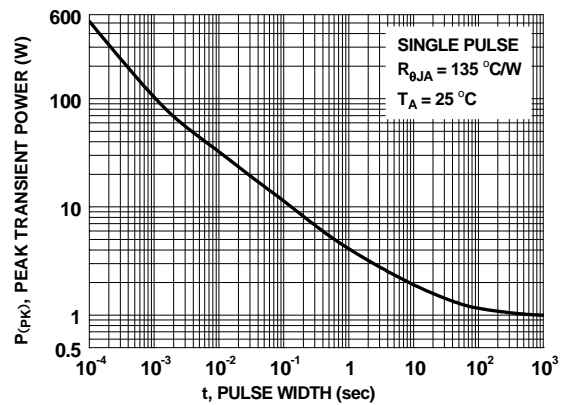
**Figure 9. Unclamped Inductive Switching Capability**



**Figure 10. Maximum Continuous Drain Current vs Ambient Temperature**

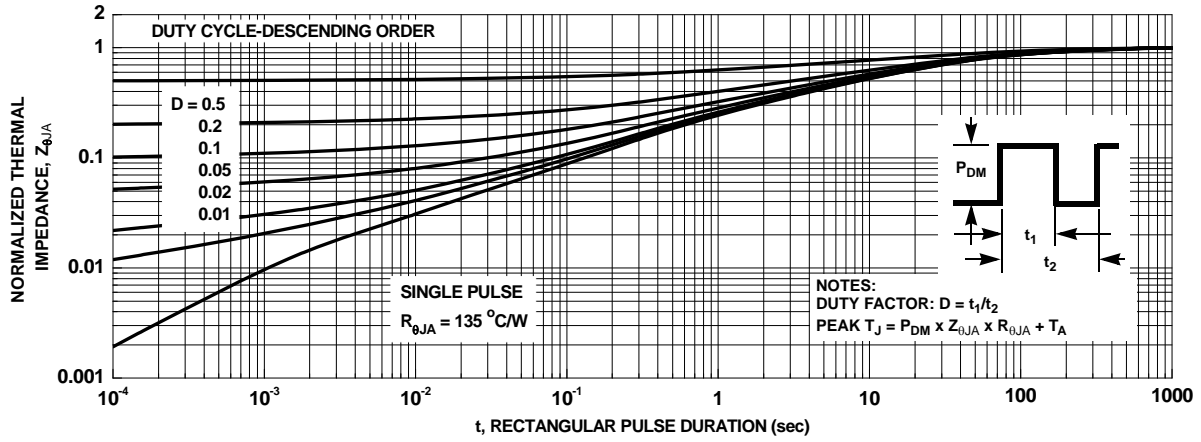


**Figure 11. Forward Bias Safe Operating Area**



**Figure 12. Single Pulse Maximum Power Dissipation**

**Typical Characteristics ( N-Channel)**  $T_J = 25^\circ\text{C}$  unless otherwise noted



**Figure 13. Junction-to-Ambient Transient Thermal Response Curve**



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